

SANYO Semiconductors DATA SHEET



Monolithic Linear IC Six-Channel Driver for Optical Disc Drives

Overview

The LA6568 is a six-channel driver for optical disc drives that includes built-in 3.3 V and 5 V regulators.

Functions

- Six power amplifier channels
- I_Omax: 700 mA
- Built-in level shifter circuits (for the BTL amplifiers)
- Muting circuit (output on/off control) for one channel
- Built-in 3.3 V power supply (I_Omax = 300 mA)
- Built-in 5 V power supply $(I_0 max = 5 mA)$
- Thermal protection circuit (thermal shutdown circuit)

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Maximum supply voltage	V _{CC} max		14	V	
Maximum output current	I _O max		0.7	Α	
Maximum input voltage	VINB max	Each channel for Ch.1 to Ch.6	13	V	
Mute pin voltage	VMUTE		13	V	
	Del morr	Mounted on a board *1	2.00	14/	
Allowable power dissipation	Pd max	Independent IC	1.20	W	
Operating temperature	Topr		-30 to +85	°C	
Storage temperature	Tstg		-55 to +150	°C	

Note *1: Mounted on a board (76.1 \times 114.3 \times 1.66 mm) Material: glass epoxy

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		6 to 13	V

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SANYO Semiconductor Co., Ltd. TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Electrical Characteristics

(Unless specified otherwise, the conditions are $Ta = 25^{\circ}C$, $S-V_{CC} = P-V_{CC} = 8 V$, VREF = 1.65 V)

Parameter	Symbol	Conditions		Ratings		Unit	
Talameter	Symbol	Conditions	min	typ	max	Offic	
[Overall]							
No load current drain - outputs on	I _{CC} -ON	All outputs on *1		30	50	mA	
No load current drain - outputs off	I _{CC} -OFF	All outputs off *1		10	20	mA	
VREF input voltage range	VREF-IN		0.5		V _{CC} -1.5	V	
[BTL Amplifier Block]							
Output offset voltage	VOFF	The voltage difference between the output amplifier outputs, for each channel	-50		+50	mV	
Input voltage range	V _{IN}		0		V _{CC}	V	
Output voltage	Vo	The voltage between the V_O+ and V_O- outputs when R_L = 8 Ω *2	4	4.5		V	
Closed circuit voltage gain 1	VG1	The gain between input and output for channels 1, 4, and 5	1.6	2	2.4	Multiplie	
Closed circuit voltage gain 2	VG2	The gain between input and output for channel 2. Input resistance: 11 $\ensuremath{k\Omega}$	3.5	4	4.5	Multiplie	
Slew rate	SR	Twice the value between each output pair *3		1		V/µs	
Muting on voltage	VMUTE-ON	For each of the muting functions *4			0.5	V	
Muting off voltage	VMUTE-OFF	For each of the muting functions *4	2			V	
[Loading Block]							
Voltage between outputs: F	VOF	V_{IN} = 2 V, V_{IN} = 0 V	2.5	2.9	3.3	V	
Voltage between outputs: R	VOR	V_{IN} + = 0 V, V_{IN} - = 2 V	-3.3	-2.9	-2.5	V	
Output voltage range: F	VOMF	V_{IN} + = 5 V, V_{IN} - = 0	4.5	5.0		V	
Output voltage range: R	VOMR	V_{IN} + = 0 V, V_{IN} - = 5 V		-5.0	-4.5	V	
Output offset voltage VOFF Potential difference between the outputs when braking is applied		-50		+50	mV		
Input current	I-IN	When $V_{IN} = 3.3 V$			500	μΑ	
[3.3 V Regulator Block]							
Output voltage	V _O -REG1	I _O = 100 mA	3.15	3.3	3.45	V	
Line regulation	ΔV-LIN1	When $I_0 = 100$ mA, $V_{CC} = 6$ to 12 V	-100		+100	mV	
Load regulation	∆V-LOAD1	When $I_0 = 0$ to 200 mA	-100		+100	mV	
[5 V Regulator Block]							
Output voltage	V _O -REG2	When I _O = 3 mA	4.75	5	5.25	V	
Line regulation	ΔV-LIN1	When $I_0 = 3$ mA, $V_{CC} = 6$ to 12 V		100		mV	
Load regulation	∆V-LOAD	When I _O = 1 to 3 mA		100		mV	
[0-RESET Block] (Operating for VREF)	· · ·			•		
High-level reset output voltage	VORH	With a 10 k $\!\Omega$ resistor between V_{CC} and RESET	6.5			V	
Low-level reset output voltage	VORL	With a 10 k Ω resistor between V_CC and RESET			0.5	V	
0-RESET threshold voltage	VRT		0.5	0.7	0.9	V	
0-RESET hysteresis	VHYS		50	100	200	mV	

Note *1: The combined current drain for P-V_{CC} and S-V_{CC} with no load

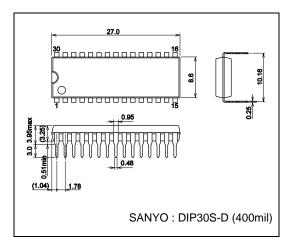
*2: The voltage difference across the load (8 Ω) terminals. With the outputs in the saturated state.

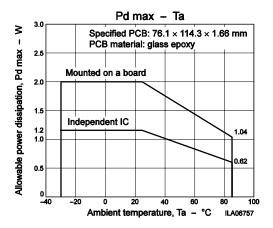
*3: Design target value. Parameters are not tested.

*4: When IN-MUTE is high: output on, when IN-MUTE is low: output off (high-impedance state)

Package Dimensions

unit: mm 3196A





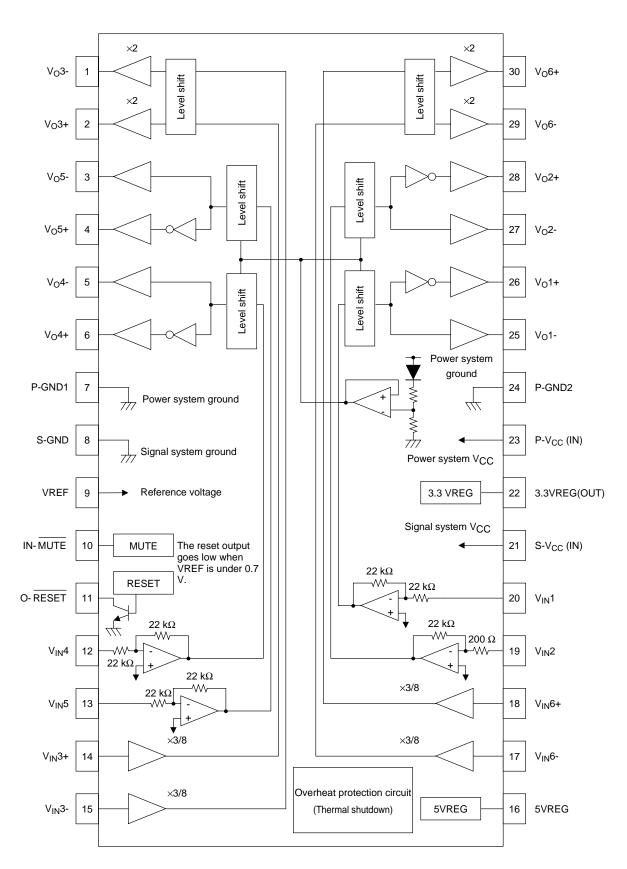
Pin Functions

Pin No.	Symbol	Pin name	Pin description	Equivalent circuit
20 19 12 13	V _{IN} 1 V _{IN} 2 V _{IN} 4 V _{IN} 5	Input	Inputs	V _{IN} O
26 25 28 27 6 5 4 3 2 1 30 29	V ₀ 1+ V ₀ 1- V ₀ 2+ V ₀ 2- V ₀ 4+ V ₀ 5+ V ₀ 5- V ₀ 3+ V ₀ 3- V ₀ 6+ V ₀ 6-	Output	Outputs	OUT
10	IN-MUTE	Mute	Controls the on/off state of the outputs. IN-MUTE high: outputs on IN-MUTE low: outputs off	V _{CC} IN-MUTE S-GND S-GND C

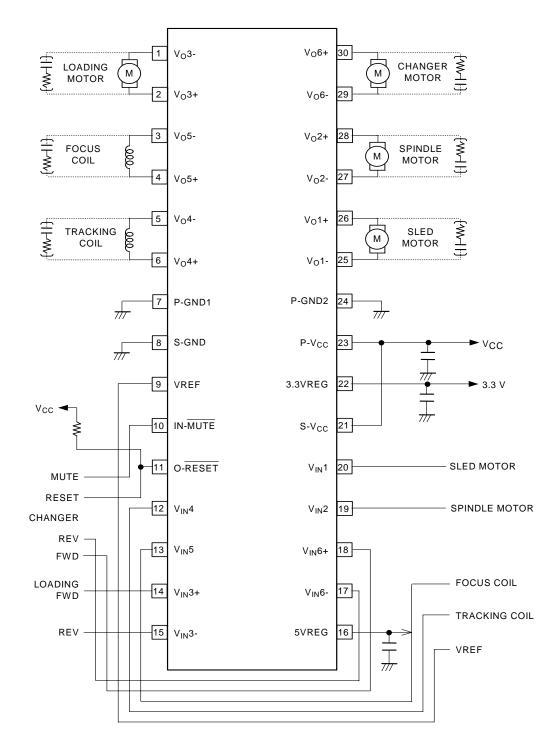
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Pin No.	Symbol	Pin name	Pin description	Equivalent circuit
11	O-RESET	Reset	Open-collector output	
15 14 17 18	V _{IN} 3- V _{IN} 3+ V _{IN} 6- V _{IN} 6+	Input (Loading block)	Inputs	
16	5VREG	5VREG	5 V regulator output	
22	3.3VREG	3.3VREG	3.3 V regulator output	The second secon

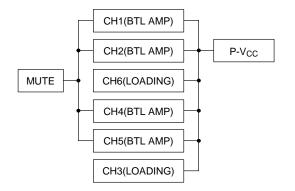
Block Diagram



Sample Application Circuit



Relationship Between Muting and the P-V_{CC} Power Supply



Note: • Connect both S-V_{CC} and P-V_{CC} to the power supply system externally. • Connect both S-GND and P-GND to the ground system externally.

Muting Functions vs. Outputs and 3.3 V Regulator Operating States

	CH1, 2, 4, 5 (BTL-AMP)	CH3, 6 (LOADING)	3.3VREG 5VREG
When IN-MUTE is low	OFF	-	OFF
When the thermal shutdown circuit has operated	OFF	OFF	OFF
When VREF has fallen below 0.7 V	OFF	-	-

Note: • A dash (-) indicates no operation for functions to which muting, thermal shutdown, or VREF fall protection apply.

• The IN-MUTE pin applies to the BTL amplifiers (channels 1, 2, 4, and 5) and the 3.3 V and 5 V regulators.

• The VREF fall protection function only applies to the BTL amplifiers.

The muting function applies to the BTL amplifiers (channels 1, 2, 4, and 5) and the 3.3 V and 5 V regulators.

IN-MUTE state	BTL-AMP 3.3VREG (CH1, 2, 4, 5) 5 VREG	
Н	ON	
L	OFF	

The VREF fall protection function only applies to the BTL amplifiers.

VREF state	BTL-AMP (CH1, 2, 4, 5)
VREF > 0.7 (V)	ON
VREF < 0.7 (V)	OFF

Loading Block

V _{IN*+} (FWD)	V _{IN} *- (REV)	Loading output
	L	Brake
L	Н	Reverse ($V_O = -1.5 \times REV$) *1
н	L	Forward ($V_0 = 1.5 \times FWD$) *1
	Н	$(V_0 = 1.5 \times (FWD - REV))$

Note *1: FWD: V_{IN}6+, V_{IN}3+, REV: V_{IN}6-, V_{IN}3-

Note: • In brake mode, the + and - output voltages both go to $V_{CC}/2$.

• The "L" voltage level is any level less than VF (approximately 0.6 V).

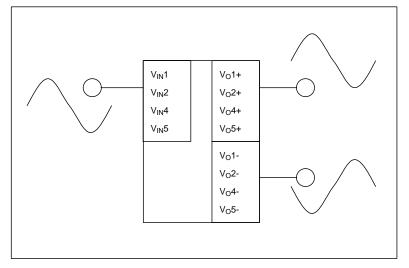
• The loading circuit (channels 3 and 6) gain is 3.5 dB (typical).

Reset Function

IN-MUTE	VREF	O-RESET
	VREF < 0.7 V	L
L	VREF > 0.7 V	L
н	VREF < 0.7 V	L
	VREF > 0.7 V	Н

Note: The O-RESET output is an open-collector output (NPN). The O-RESET low state is when the NPN transistor output is on, and the O-RESET high state is when the NPN transistor output is off.





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